BGA728L7

Broadband Low Noise Amplifier for Portable and Mobile TV Applications

Small Signal Discretes



Never stop thinking

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BGA728L7

Revisio	n History: 2009-01-20, Rev. 2.0
Previou	s Version: 2008-09-25, Rev. 1.2
Page	Subjects (major changes since last revision)
All	Status changed from preliminary to final data sheet



Broadband Low Noise Amplifier for Portable and Mobile TV Applications

Broadband Low Noise Amplifier for Portable and Mobile TV Applications

Features

1

- High gain mode: 15.75 dB gain
- Low gain mode: -5.2 dB gain
- Noise figure: 1.3 / 5.5 dB in high / low gain mode
- Power off function ٠
- Operating frequency: 100 ~ 1700 MHz
- Supply voltage: 1.5 V to 3.6 V ٠
- Small leadless TSLP-7-1 package (2.0 x 1.3 x 0.4 mm³) ٠
- Output internally matched to 50 Ω ٠
- Input pre-matched to 50 Ω ٠
- Low external component count
- Integrated ESD protection (1 kV HBM)
- Moisture sensitivity level: MSL 1
- Pb-free (RoHS compliant) package



Applications

- Portable and mobile TV in VHFIII-, UHF- and L-bands
- ISM applications in 100... 1700 MHz











Description

2 Description

The BGA728L7 is a low power low noise amplifier (LNA) MMIC for portable and mobile TV applications in the VHFIII-, UHF- and L-Bands. The low gain mode with much higher linearity enables this LNA to work with much lower current consumption than commonly used TV LNAs. The LNA is based upon Infineon Technologies cost effective B7HFM Silicon Germanium technology and comes into a low profile TSLP-7-1 leadless green package. This document specifies the electrical parameters, pin-out, application circuit and packaging of the chip.

Туре	Package	Marking
BGA728L7	TSLP-7-1	AP

Pin Definition and Function

Table 1Pin Definition and Function	
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Pin No.	Symbol	Function	
1	GS	High-gain / Low-gain control	
2	RFin	RF input	
3	BIAS	Bias voltage	
4	PON	Power on / off control	
5	RFout	RF output	
6	VCC	Supply voltage	
7	GND	DC/RF ground	

Maximum Ratings

Table 2Maximum Ratings

Parameter ¹⁾	Symbol	Value	Unit
Voltage at pin VCC	V _{CC}	-0.3 3.6	V
Voltage at pin RF_IN	V _{RFIN}	-0.3 0.9	V
Voltage at pin RF_OUT	V _{RFOUT}	-0.3 V _{CC} + 0.3	V
Voltage at pin PON	V _{PON}	-0.3 V _{CC} + 0.3	V
Current into pin VCC	I _{CC}	20	mA
RF input power	P _{IN}	10	dBm
Total power dissipation	P _{tot}	72	mW
Junction temperature	T _J	150	°C
Ambient temperature range	T _A	-40 85	°C
Storage temperature range	T _{STG}	-65 150	°C
ESD integrity HBM ²⁾	V _{ESD}	1	kV

1) All voltages refer to GND-Node.

2) According to JESD22-A114



Electrical Characteristics

Thermal resistance

Table 3 Thermal resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R _{thJS}	240	K/W

1) For calculation of R_{thJA} please refer to Application Note Thermal Resistance

3 Electrical Characteristics

Table 4DC Characteristics: T_A = 25 °C ; V_{CC} = 2.8 V, unless otherwise stated; no RF input signal

Parameter	Symbol		Value	s	Unit	Note / Test Condition
		Min.	Тур.	Max.		
Supply voltage	V _{CC}	1.5		3.6	V	
Supply current high gain mode	I _{CCHG}		5.85		mA	
Supply current low gain mode	I _{CCLG}		0.55		mA	
Supply current at shutdown	I _{OFF}			5	μA	
Logic levels PON pin	V_{PON}	1.5		3.3	V	High
		0		0.4	V	Low
Current into PON pin	I _{PON}		25		μA	V_{Pon} = High, V_{GS} = Low
			35		μA	V_{Pon} = High, V_{GS} = High
			5		μA	V_{Pon} = Low, V_{GS} = High
				2	μA	V_{Pon} = Low, V_{GS} = Low
Logic levels GS pin	V _{GS}	1.5		3.3	V	High
		0		0.4	V	Low
Current into GS pin	I _{GS}		35		μA	$V_{\rm GS}$ = High
				2	μA	$V_{\rm GS}$ = Low



Electrical Characteristics

Parameter	Symbol Values			Unit	Note / Test Condition		
		Min.	Тур.	Max.			
Frequency Range	F _{BW}	170 ²⁾		1675	MHz	VHFIII/UHF/L-Band US/L-Band EU	
Power Gain	S ₂₁		15.75		dB	<i>f</i> = 470MHz	
Power Gain Variation over Frequency	$\Delta S_{21} $		1		dB	<i>f</i> = 170 MHz-1675 MHz	
Reverse Isolation	1/ S ₁₂		>25		dB		
Noise figure ³⁾	NF		1.3		dB	<i>f</i> = 470 MHz	
Input return loss	1/ S ₁₁		>8		dB	50 Ω	
Output return loss	$1/ S_{22} $		>8		dB	50 Ω	
Stability factor ³⁾	k		>1.5			From 30 kHz to 6 GHz	
Input 1 dB compression point ³⁾ I	IP _{1dB}		-10		dBm	<i>f</i> = 170 MHz	
			-10		dBm	<i>f</i> = 470 MHz	
			-9		dBm	<i>f</i> = 1500 MHz	
3rd order input intercept point ³⁾	IIP ₃		-7		dBm	<i>f</i> = 170 MHz; 1 MHz offset	
			-7		dBm	<i>f</i> = 470 MHz; 1 MHz offset	
			-3		dBm	<i>f</i> = 1500 MHz; 1 MHz offset	
Settling time for Power On ³⁾	t _{PON}		3.5		μs		
Settling time Power Off ³⁾	t _{POFF}		2		μs		

Typical RF Characteristics¹⁾ High-Gain Mode: T_{A} = 25 °C, V_{CC} = 2.8 V, V_{PON} = 2.8 V, V_{GS} = 0 V Table 5

1) Measured on BGA728L7 application board without substracting PCB losses (unless noted otherwise) at 470 - 1675 MHz

2) 170 MHz to 240 MHz (VHF III) can be covered by adding external capacitor on input circuit (see Application Information)

3) Verify by random sampling



Electrical Characteristics

Parameter	Symbol		Value	S	Unit	Note / Test Condition
		Min.	Тур.	Max.		
Frequency Range	F _{PW}	170 ²⁾		1675	MHz	VHFIII/UHF/L-Band US/L-Band EU
Power Gain	S ₂₁		-5.2		dB	
Power Gain Variation over Frequency	$\Delta S_{21} $		2.1		dB	<i>f</i> = 170 MHz-1675 MHz
Noise figure ³⁾	NF		5.5		dB	<i>f</i> = 470 MHz
Input return loss	1/ S ₁₁		>8		dB	50 Ω
Output return loss	1/ S ₂₂		>8		dB	50 Ω
Input compression point ³⁾	IP _{1dB}		3		dBm	<i>f</i> = 170 MHz
			3.5		dBm	<i>f</i> = 470 MHz
			5		dBm	<i>f</i> = 1500 MHz
3rd order input intercept point ³⁾	IIP ₃		16		dBm	<i>f</i> = 170 MHz; 1 MHz offset
			16		dBm	f = 470 MHz; 1 MHz offset
			20		dBm	<i>f</i> = 1500 MHz; 1 MHz offset
Settling time GS ON ³⁾	t _{GSON}		2		μs	
Settling time GS OFF ³⁾	t _{GSOFF}		3.5		μs	

Table 6Typical RF Characteristics¹⁾ Low-Gain Mode: $T_A = 25 \,^{\circ}\text{C}$, $V_{CC} = 2.8 \,\text{V}$, $V_{PON} = 2.8 \,\text{V}$, $V_{GS} = 2.8 \,\text{V}$

1) Measured on BGA728L7 application board including PCB losses (unless noted otherwise) at 470 - 1675 MHz

2) 170 MHz to 240 MHz (VHF III) can be covered by adding external capacitor on input circuit (see Application Information)

3) Verify by random sampling

Gain Mode Selection Truth Table

Control Voltage V _{PON} ¹⁾	Control Voltage $V_{GS}^{1)}$	Gain Mode
High	Low	High Gain
High	High	Low Gain
Low	High	Low Gain
Low	Low	OFF

1) See **Table 4** for the High/Low voltage range



Typical Measured Results

4 Typical Measured Results

T_{A} = 25 °C, V_{CC} = 2.8 \lor , V_{PON} = 2.8 \lor , V_{GS} = 0 \lor for High Gain Mode, V_{GS} = 2.8 \lor for Low Gain Mode

Note: Measurements based on VHF-board application. For UHF application NF can be further optimized by omitting the optional capacitor C5.

Note: Board losses are not substracted

Gain $|S_{21}| = f(f)$

Isolation $|S_{12}| = f(f)$







Typical Measured Results

Input Return Loss $|S_{11}| = f(f)$



Output Return Loss $|S_{22}| = f(f)$



IRLvsd



High Gain Noise Figure *NF* = f (*f*)



NF.vsd

High Gain Stability Factor *k* = f (*f*)



K_factor.vsd



Application Information

5 Application Information

Application Circuit



Figure 2 Application circuit of BGA728L7

Table 7 Bill of Materials

Name	Value	Package	Manufacturer	Function
C1	56 pF	0402	Various	DC block
C4	1 nF	0402	Various	Supply voltage filtering
C5	1 nF	0402	Various	Optional for VHF-band
L1	75 nH	0402	Murata LQW15AN75NG00	Bias Feed
N1	BGA728L7	TSLP-7-1	Infineon	SiGe LNA
C2, C3	not used			

A list of all application notes including AN163 in particular for BGA728L7 is available at http://www.infineon.com/MobileTVLNA



Application Information

Application Board



Figure 3 Application Board







Figure 5 Recommended Land Pattern



Package Information

6 Package Information



Figure 6 Package Dimensions for TSLP-7-1



Figure 7 Tape & Reel Dimensions (Ø reel 180, pieces/reel 7500)



